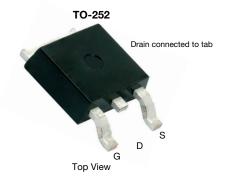


Automotive N-Channel 40 V (D-S) 175 °C MOSFET

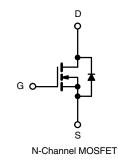
PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0036				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0042				
I _D (A)	100				
Configuration	Single				
Package	TO-252				



FEATURES

- TrenchFET[®] power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified ^d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ABSOLUTE MAXIMUM RATING	GS (T _C = 25 °C, unless	otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	40	V
Gate-Source Voltage		V _{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C ª	۱ _D	100	А
Continuous Drain Current	T _C = 125 °C		80	
Continuous Source Current (Diode Conduc	tion) ^a	I _S	100	
Pulsed Drain Current ^b		I _{DM}	400	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	55	
Single Pulse Avalanche Energy		E _{AS}	151	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	D	136	W
Maximum Fower Dissipation ~	T _C = 125 °C	P _D	45	vv
Operating Junction and Storage Temperation	ure Range	T _J , T _{stq}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W
Junction-to-Case (Drain)		R _{thJC}	1.1	0/10

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		40	-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		-	2.5	v
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	Α
		$V_{GS} = 10 V$	I _D = 20 A	-	0.0030	0.0036	Ω
Drain Course On State Desistance a		$V_{GS} = 10 V$	I _D = 20 A, T _J = 125 °C	-	-	0.0058	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.0070	
		$V_{GS} = 4.5 V$	I _D = 20 A	-	0.0035	0.0042	
Forward Transconductance b	g fs	V _{DS}	= 15 V, I _D = 15 A	-	105	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	4880	5860	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	560	670	
Reverse Transfer Capacitance	C _{rss}			-	250	300	
Total Gate Charge ^c	Qg			-	85	130	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 50 \text{ A}$	-	14	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	14	-	
Gate Resistance	R _g	f = 1 MHz		0.6	1.5	3	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	9	11	
Rise Time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 20 \text{ V}, \ R_{\text{L}} = 0.4 \ \Omega \\ I_{\text{D}} \cong 50 \text{ A}, \ V_{\text{GEN}} = 10 \text{ V}, \ R_{\text{g}} = 1 \ \Omega \end{array}$		-	11	14	ns
Turn-Off Delay Time ^c	t _{d(off)}			-	39	47	
Fall Time ^c	t _f			-	11	14	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	400	Α
		I _F = 30 A, V _{GS} = 0 V					

Notes

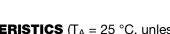
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



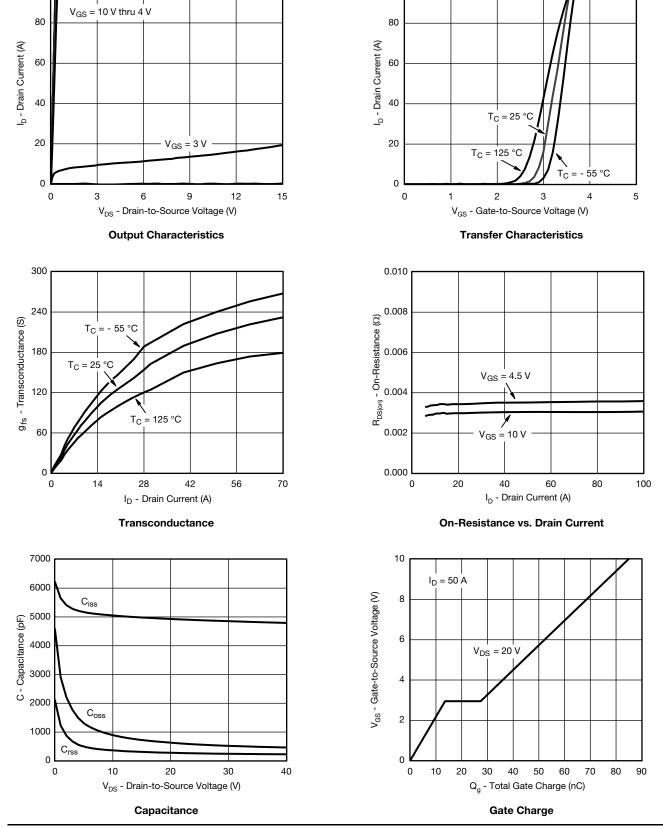
SQD100N04-3m6L

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

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S15-1874-Rev. B, 10-Aug-15

Document Number: 63837

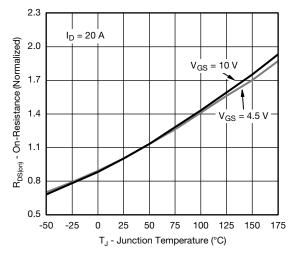
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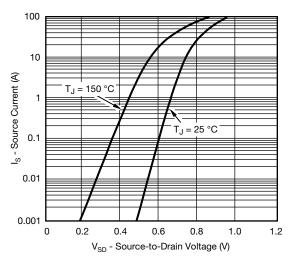
SQD100N04-3m6L

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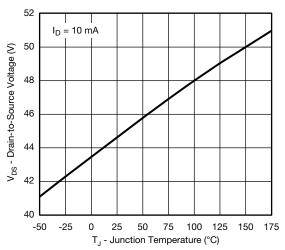
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



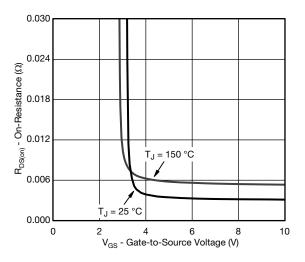
On-Resistance vs. Junction Temperature



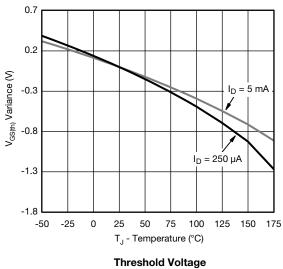
Source Drain Diode Forward Voltage



Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



S15-1874-Rev. B, 10-Aug-15

4

Document Number: 63837

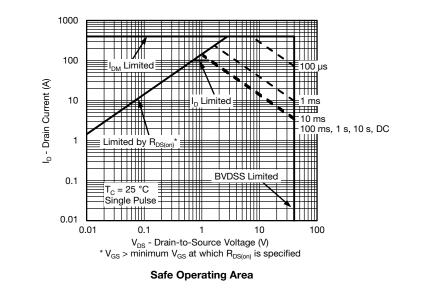
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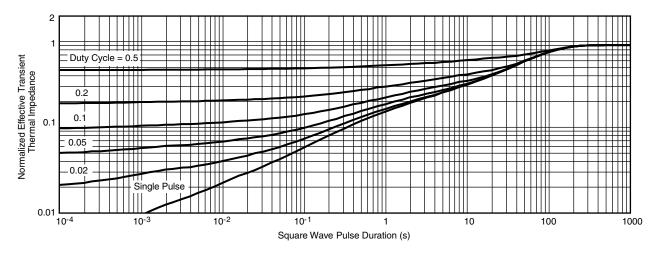


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

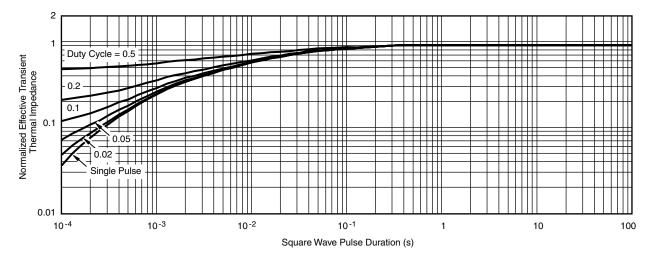




Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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SQD100N04-3m6L

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REVISION	HISTORY ^a	
REVISION	DATE	DESCRIPTION OF CHANGE
В	04-Aug-15	Revised R _g minimum limit

Note

a. As of April 2014





Е b3 Ľ Δ ŝ b2 e1 Б E1

C2 т gage plane height (0.5 mm)

-C

- A1

TO-252AA Case Outline

	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019					

Note

• Dimension L3 is for reference only.





RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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